

FM IF amplifier and detector

Technology: Bipolar

Features

- No selection of volume-input characteristics
- Independent sound output for VTR and headphone
- Additional sound input
- High ripple rejection
- High residual carrier suppression prevents harmonic distortions

Case: 14 pin dual inline plastic

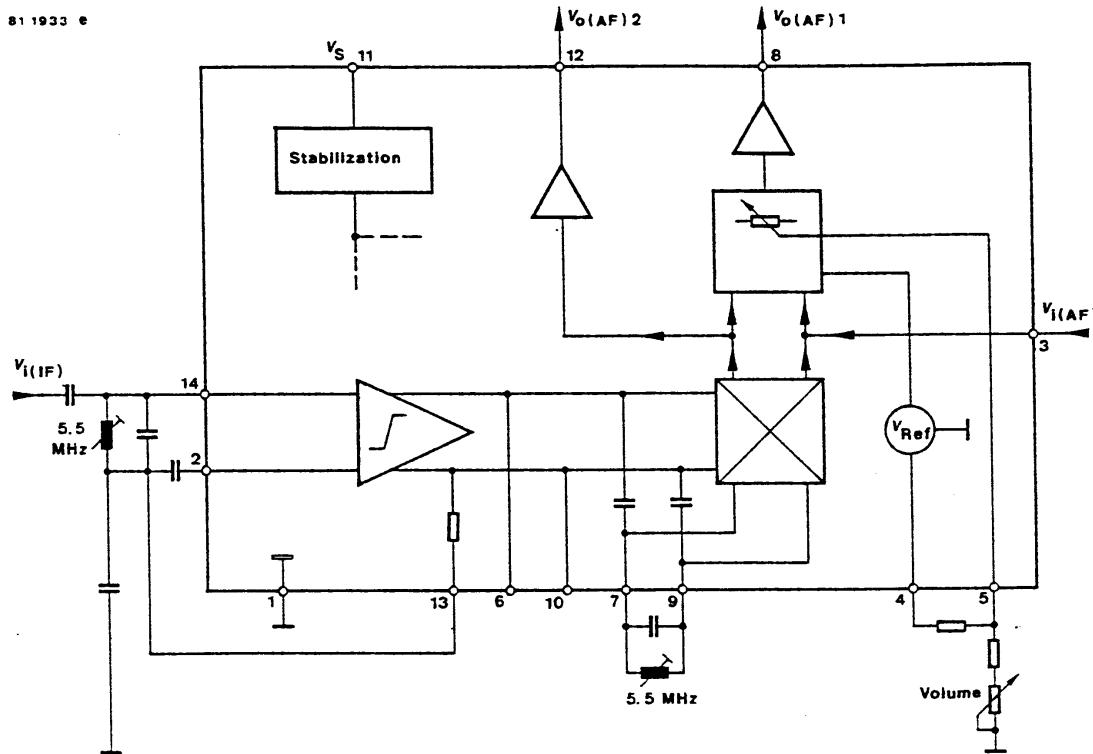


Figure 1 Block diagram

Absolute Maximum Ratings

Reference point pin 1, unless otherwise specified

Parameters	Symbol	Value	Unit
Supply voltage	V_S	18	V
Volume setting voltage	V_5	6	V
Reference supply current	I_{Ref}	5	mA
Resistor between pin 13 and pin 14	R_p	1	k Ω
Power dissipation $T_{amb} = 60^\circ\text{C}$	P_{tot}	400	mW
Ambient temperature range	T_{amb}	-15 to +70	°C
Storage temperature range	T_{stg}	-25 to +125	°C

Electrical CharacteristicsT_{amb} = +25°C, V_S = 12 V, f = 5.5 MHz, figure 3, reference point pin 1, unless otherwise specified

Parameters	Test Conditions / Pins	Symbol	Min.	Typ.	Max.	Unit
Supply voltage range	Pin 11	V _S	10		18	V
Supply current	Pin 11	I _S	9.5		17.5	mA
Reference voltage	Pin 4	V _{oRef}	4.2	4.8	5.5	V
Output resistance	Pin 4	r _{Ref}		12		Ω
Frequency range		f		0 to 12		MHz
IF voltage amplification	Pin 6/14	G _{IF}		68		dB
IF output voltage	when limited, each output Pin 6/10	V _{o(IF)pp}		250		mV
Input limiting voltage	Δf = ± 50 kHz, f _{mod} = 1 kHz, Q ≈ 45 ¹⁾ Pin 14	V _{i(IF)}		30	60	μV
Input impedance	Pin 14	R _i C _i	15	40 4.5	6	kΩ pF
AM rejection	Δf = ± 50 kHz, Q ≈ 45 ¹⁾ , f _{mod} = 1 kHz, m = 30 %, V _i = 500 μV	k _{AM}	50	60		dB
DC voltage at AF output	V _i = 0 V Pin 8 Pin 12	V _{o(AF)1} V _{o(AF)2}		4 5.6		V V
Ripple rejection	Pin 11/8 Pin 11/12	k _{Br} k _{Br}		35 30		dB dB
IF residual voltage	without de-emphasis capacitor Pin 8 Pin 12	V _{o(IF)1} V _{o(IF)2}		20 30		mV mV
AF output voltage	V _i = 10 mV, R ₅ = 20 kΩ, Δf = ± 50 kHz, f _{mod} = 1 kHz, Q = 45 ¹⁾ , k = 4% Q = 20 ¹⁾ , k = 1% Pin 8 Pin 12	V _{o(AF)1} V _{o(AF)2}		1.3 1.0		V V
	Pin 8 Pin 12	V _{o(AF)1} V _{o(AF)2}		0.65 0.5		V V
Input resistance	Pin 3	r _i		2		kΩ
Output resistance	Pin 8, 12	r _o		1.1		kΩ
AF voltage gain	R ₅ = 20 kΩ	G _{v1}		7.5		dB
AF damping Fig. 3	R ₅ = 13 kΩ	-G _{v1}	20	28	36	dB
Volume setting range	Pin 8	ΔV _{o(AF)1}	70	85		dB
Mute function						
Switching current	figure 2 Pin 2 or 13	I _{sw}			400	μA
Switching voltage		V _{mute}	3			V

¹⁾ Operation quality factor

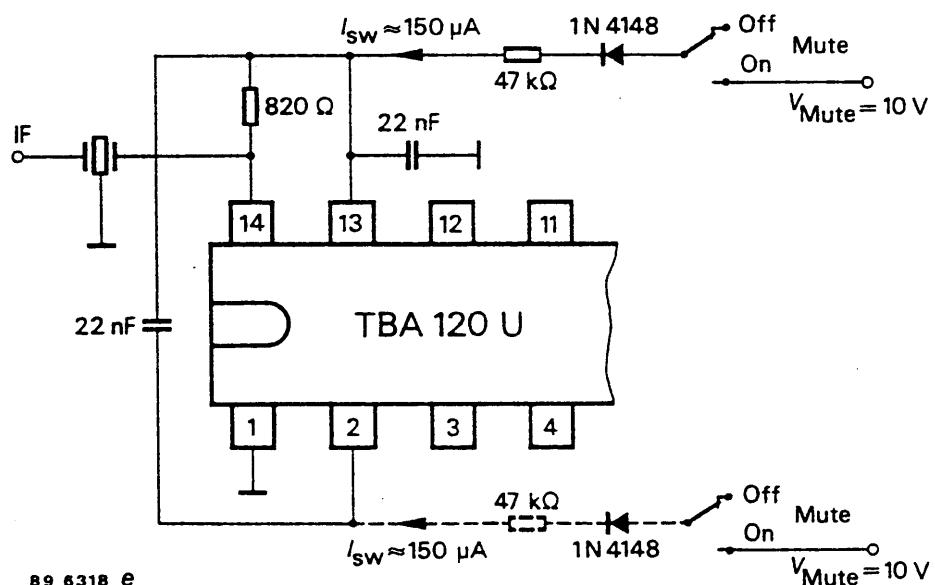


Figure 2

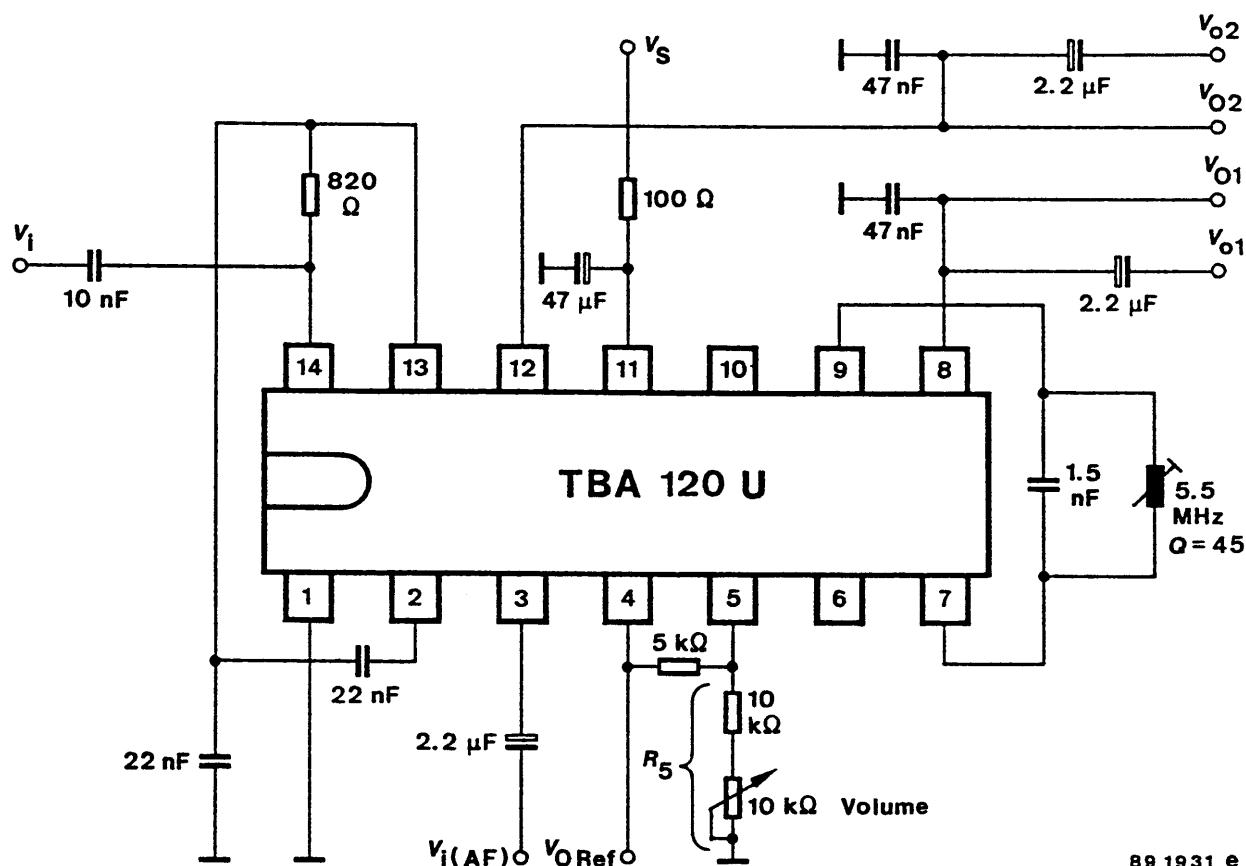


Figure 3 Test circuit

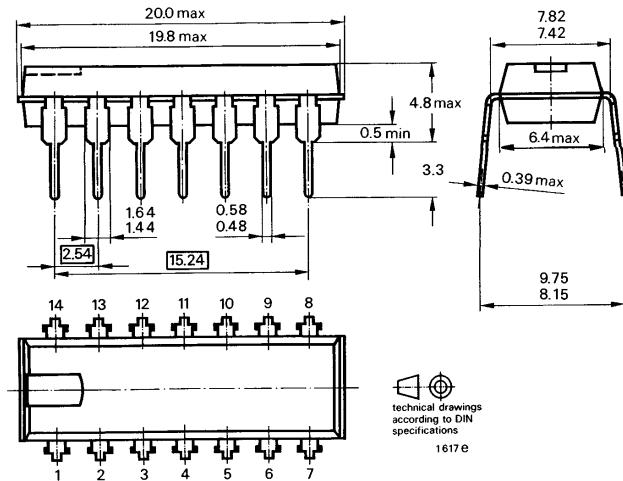
TBA120U

TEMIC

TELEFUNKEN Semiconductors

Dimensions in mm

Package: JEDEC MO 001, DIP 14



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